NSN 5961-00-808-8398

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View Online at https://aerobasegroup.com/nsn/5961-00-808-8398 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.359 inches **Internal Configuration:** Unijunction **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pn **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 70.00 milliamperes source cutoff current blank **Power Rating Per Characteristic:** 600.00 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/75 government specification Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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